

Fig. 1

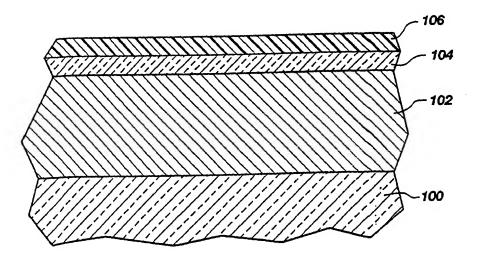


Fig. 2

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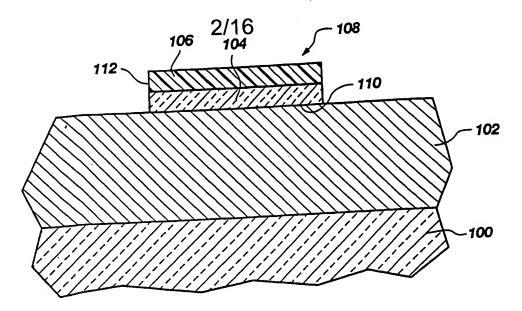


Fig. 3

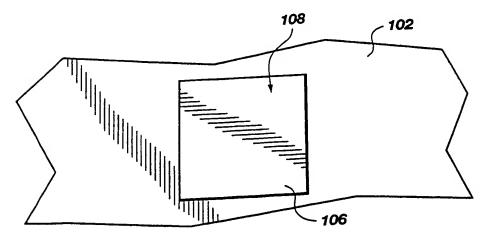


Fig. 4a

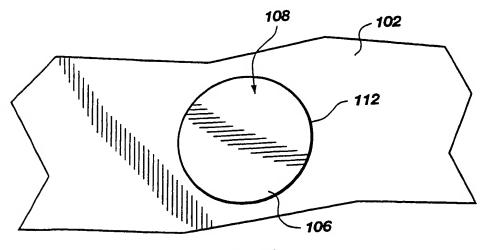


Fig. 4b

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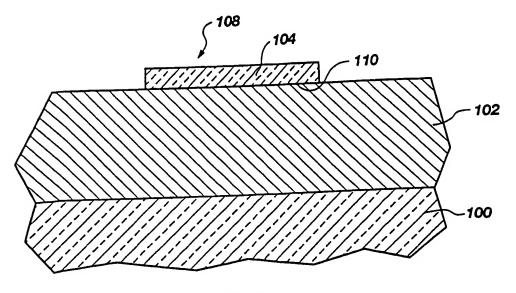


Fig. 5

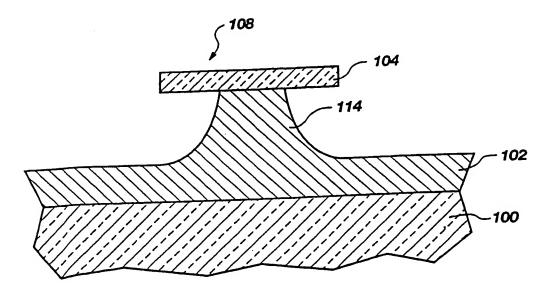


Fig. 6

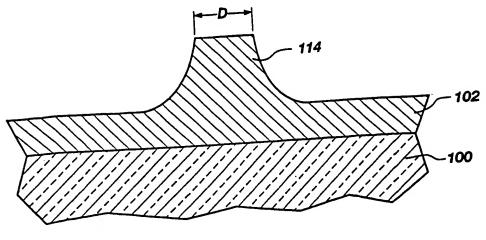


Fig. 7

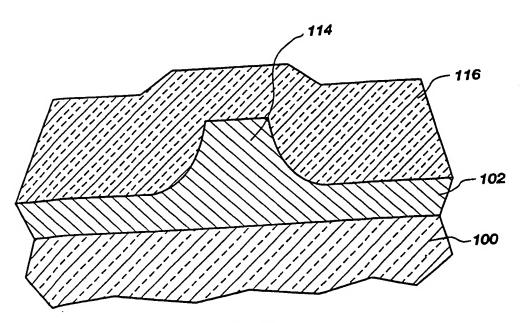
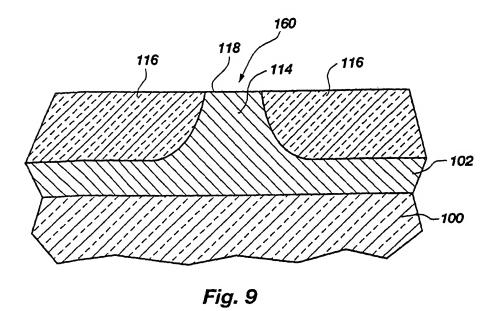
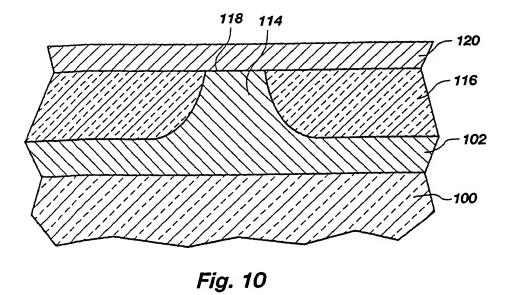


Fig. 8

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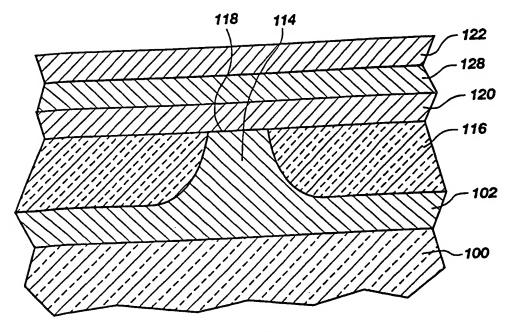


Fig. 11

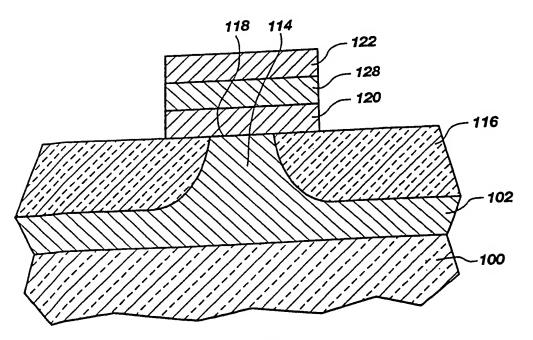


Fig. 12

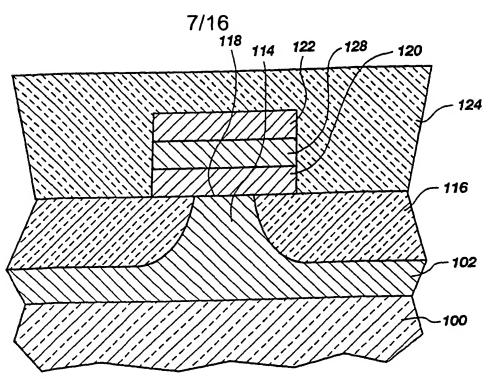


Fig. 13

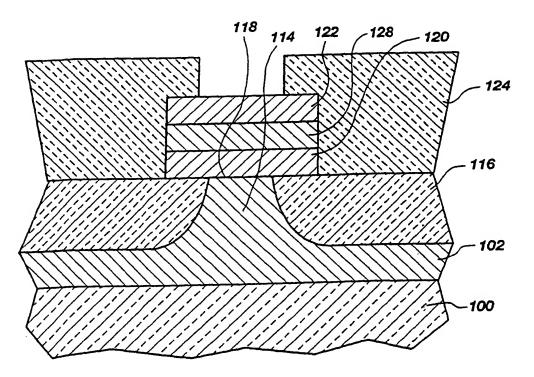
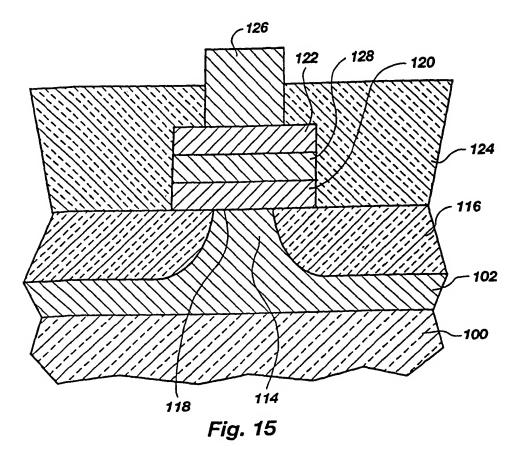


Fig. 14



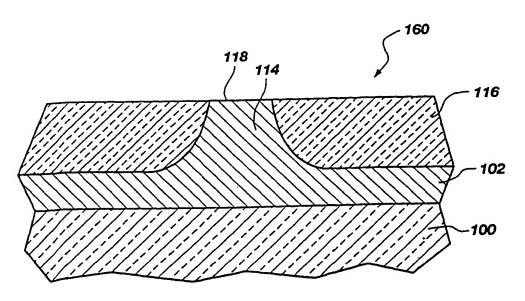


Fig. 16

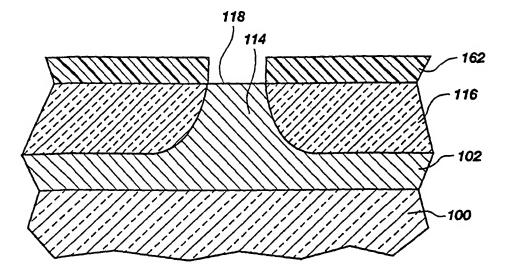
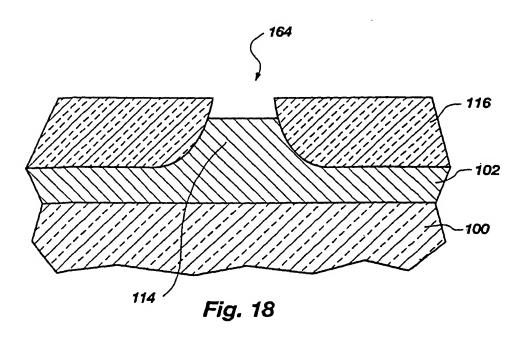
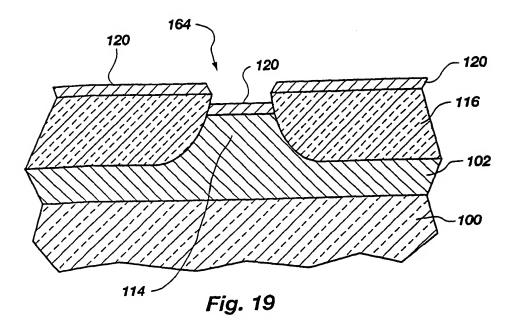
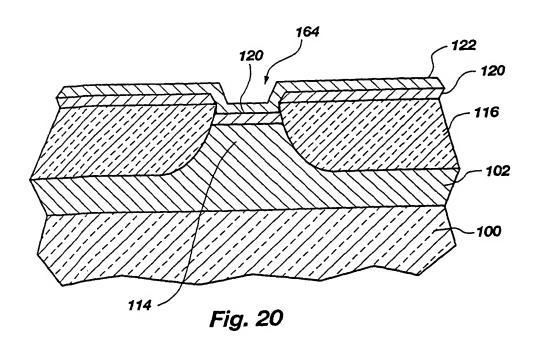


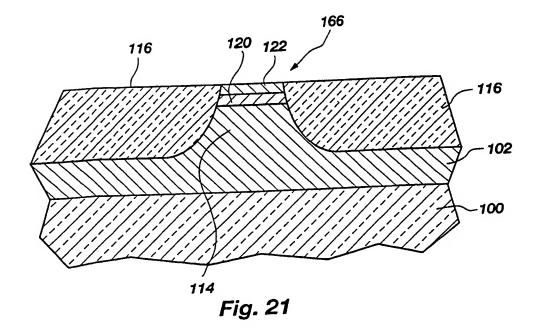
Fig. 17







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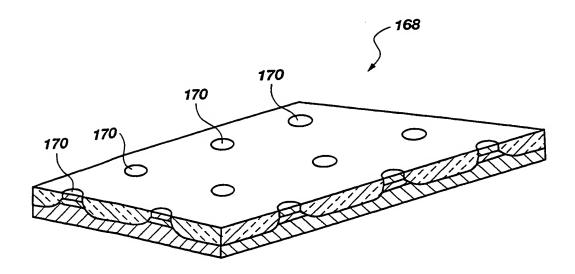
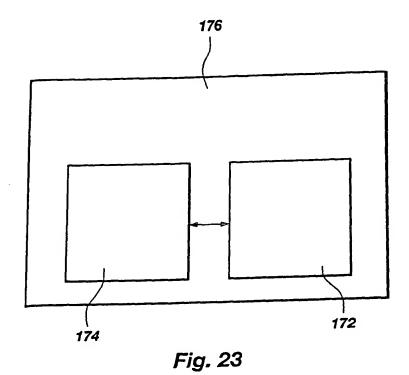


Fig. 22



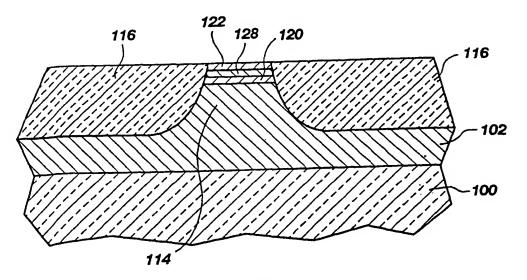


Fig. 24

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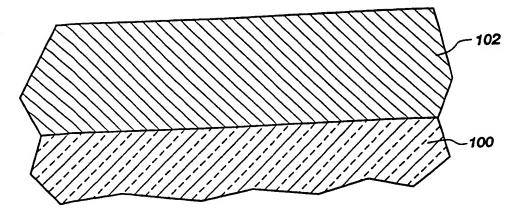


Fig. 25

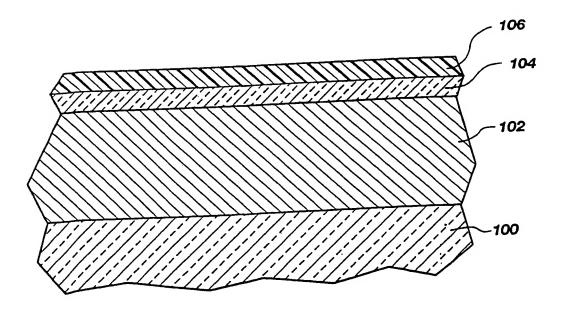


Fig. 26

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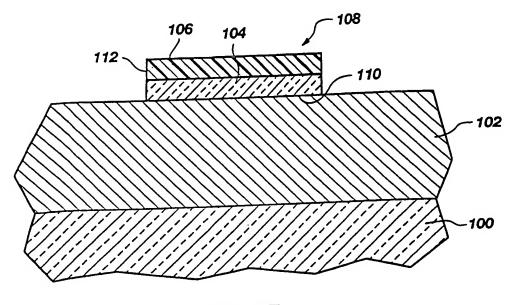


Fig. 27

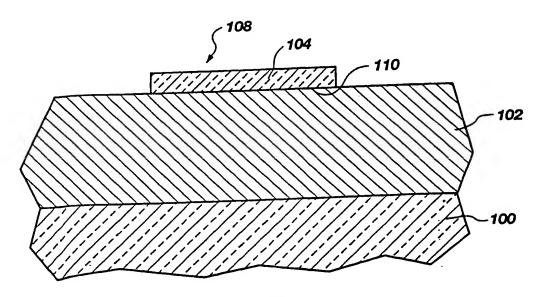


Fig. 28

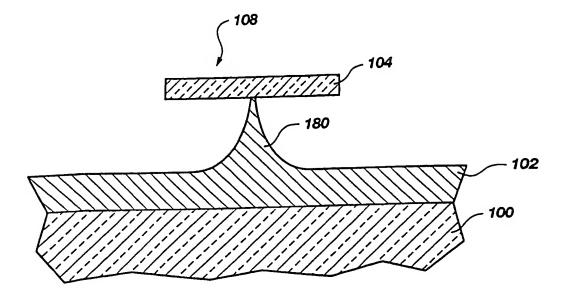


Fig. 29

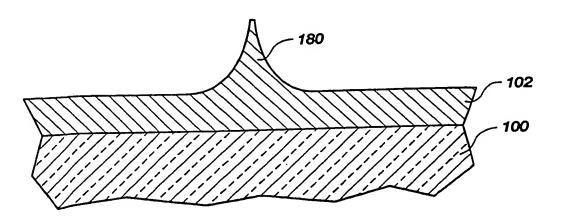
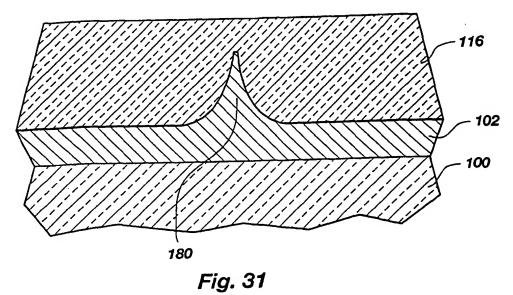


Fig. 30

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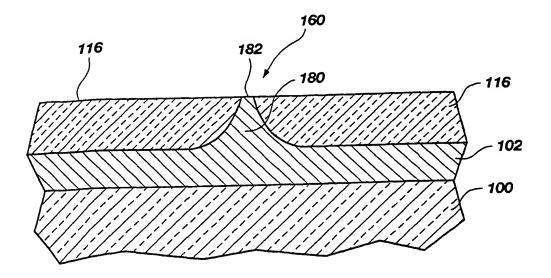


Fig. 32